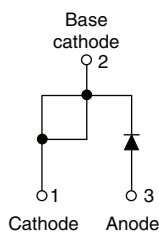


Schottky Rectifier, 10 A



TO-220AC



FEATURES

- 150 °C T_J operation
- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)



PRODUCT SUMMARY

Package	TO-220AC
I _{F(AV)}	10 A
V _R	35 V, 45 V
V _F at I _F	0.57 V
I _{RM} max.	15 mA at 125 °C
T _J max.	150 °C
Diode variation	Single die
E _{AS}	8 mJ

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	10	A
I _{FRM}	T _C = 135 °C	20	
V _{RRM}		35/45	V
I _{FSM}	t _p = 5 μs sine	1060	A
V _F	10 A _{pk} , T _J = 125 °C	0.57	V
T _J	Range	- 65 to 150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-MBR1035PbF	VS-MBR1035-N3	VS-MBR1045PbF	VS-MBR1045-N3	UNITS
Maximum DC reverse voltage	V _R	35	35	45	45	V
Maximum working peak reverse voltage	V _{RWM}					

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 135 °C, rated V _R	10	A
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 135 °C	20	
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	1060	A
		Following any rated load condition and with rated V _{RRM} applied	150	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 4 mH	8	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _R typical	2	A

**ELECTRICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	T _J = 25 °C	0.84	V
		10 A	T _J = 125 °C	0.57	
		20 A		0.72	
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA
		T _J = 125 °C		15	
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		0.354	V
Forward slope resistance	r _t			17.6	mΩ
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		600	pF
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/μs

Note(1) Pulse width < 300 μ s, duty cycle < 2 %**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J		- 65 to 150	°C
Maximum storage temperature range	T _{Stg}		- 65 to 175	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.0	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (only for TO-220)	0.50	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-220AC	MBR1035	
			MBR1045	

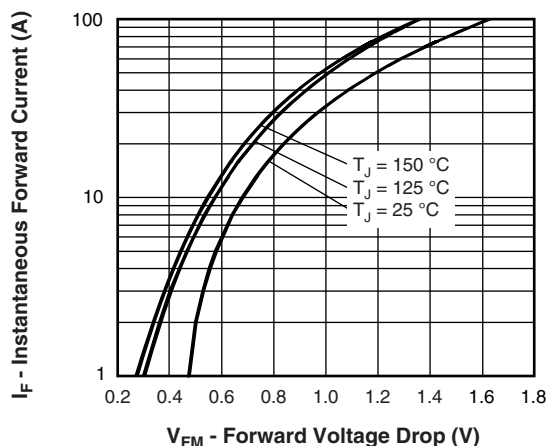


Fig. 1 - Maximum Forward Voltage Drop Characteristics

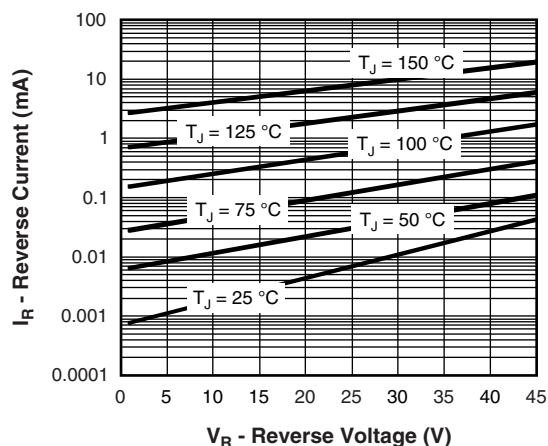


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

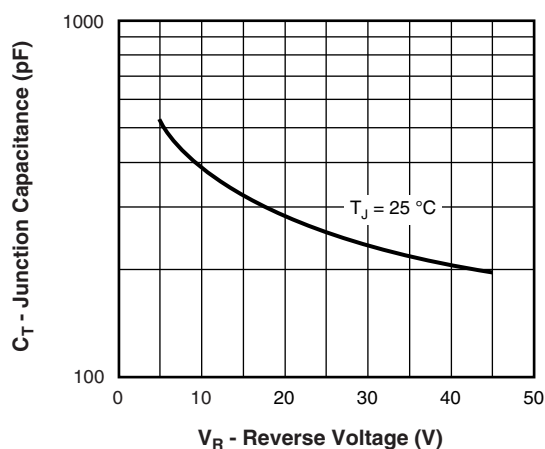


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

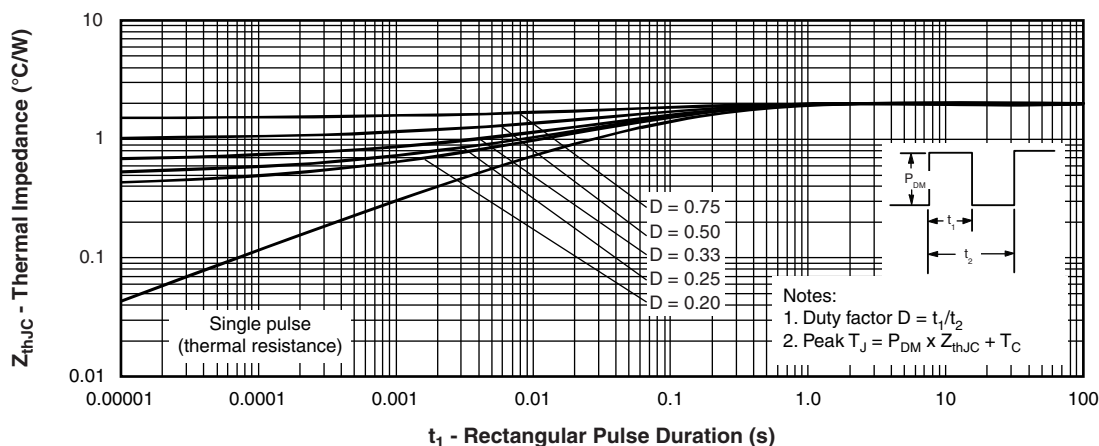


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

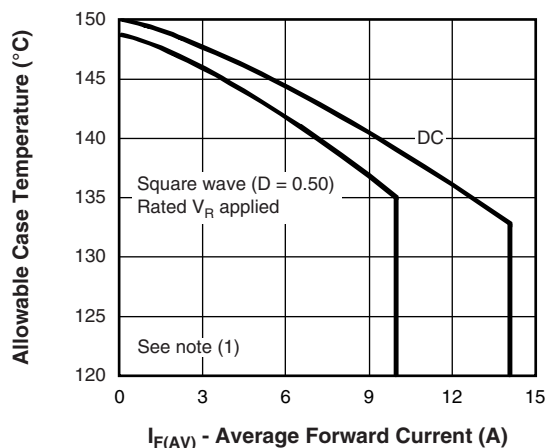


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

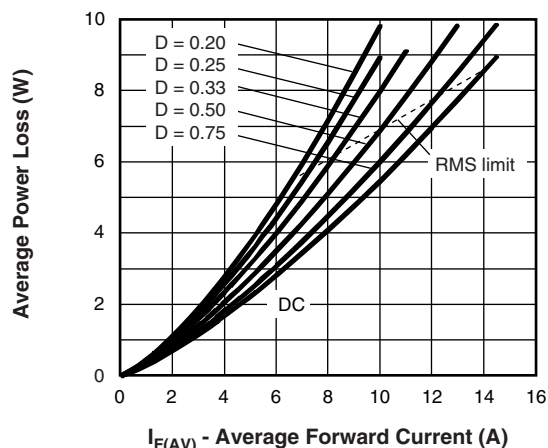


Fig. 6 - Forward Power Loss Characteristics

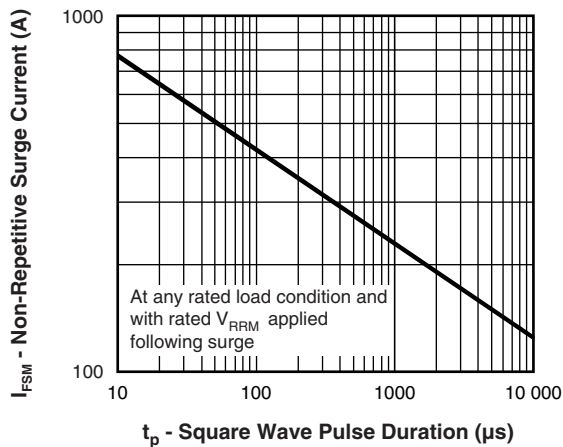


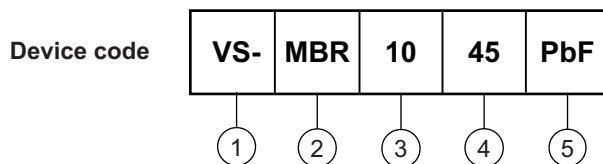
Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Schottky MBR series
- 3** - Current rating (10 = 10 A)
- 4** - Voltage ratings

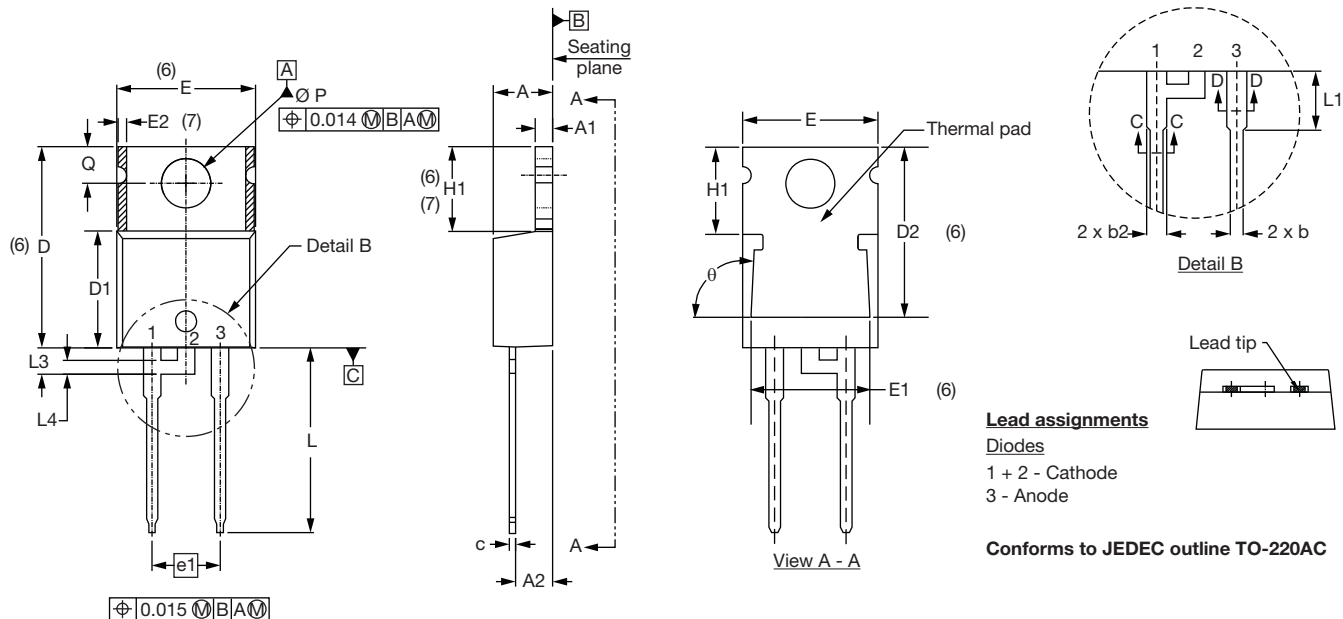
35 = 35 V
45 = 45 V
- 5** - Environmental digit
 - PbF = Lead (Pb)-free and RoHS compliant
 - -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-MBR1035PbF	50	1000	Antistatic plastic tube
VS-MBR1035-N3	50	1000	Antistatic plastic tube
VS-MBR1045PbF	50	1000	Antistatic plastic tube
VS-MBR1045-N3	50	1000	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95221
Part marking information	TO-220AC PbF www.vishay.com/doc?95224
	TO-220AC -N3 www.vishay.com/doc?95068
SPIICE model	www.vishay.com/doc?95293

TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
c	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
E	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
Ø P	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° to 93°		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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